

TYNx10 Series

10A SCR

STANDARD

Table 1: Main Features

Symbol	Value	Unit
I _{T(RMS)}	10	А
V _{DRM} /V _{RRM}	400, 600 and 800	V
I _{GT}	15	mA

DESCRIPTION

The **TYNx10** Silicon Controlled Rectifiers is a high performance glass passivated technology.

This general purpose Silicon Controlled Rectifiers is designed for power supply up to 400Hz on resistive or inductive load.



Table 2: Order Codes

Part Numbers	Marking
TYN410RG	TYN410
TYN610RG	TYN610
TYN810RG	TYN810

Table 3: Absolute Ratings (limiting values)

Symbol	Parameter	Value	Unit			
I _{T(RMS)}	RMS on-state current (180° conduction	10	Α			
$IT_{(AV)}$	Average on-state current (180° conduct	ion angle)	$T_c = 100^{\circ}C$	6.4	А	
l-ou	Non repetitive surge peak on-state	t _p = 8.3 ms	T _i = 25°C	105	А	
ITSM	current	t _p = 10 ms	$1_j = 250$	100		
l ² t	I ² t Value for fusing	t _p = 10 ms	T _j = 25°C	50	A ² s	
dl/dt	Critical rate of rise of on-state current $I_G = 100 \text{ mA}$, $dI_G/dt = 0.1 \text{ A}/\mu\text{s}$		T _j = 125°C	50	A/µs	
I _{GM}	Peak gate current t _p = 20 µs		T _j = 125°C	4	А	
$P_{G(AV)}$	Average gate power dissipation		T _j = 125°C	1	W	
P_{GM}	Maximum gate power $t_p = 20 \ \mu s$		T _j = 125°C	10	W	
V _{DRM}		TYN410		400		
V _{RRM}	Repetitive peak off-state voltage	TYN610	T _j = 125°C	600	V	
* RRM		TYN810	-	800		
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125	°C	
ΤL	Maximum lead temperature for soldering during 10s at 2mm from case			260	°C	

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Symbol	Test Conditions		Value	Unit	
I _{GT}	$V_{\rm D} = 12 {\rm V} ({\rm D.C.}) {\rm R}_{\rm I} = 33 {\Omega}$		MAX.	15	mA
V _{GT}	$V_{\rm D} = 12 V (D.0.) + 11 = 33.32$		MAX.	1.5	V
V_{GD}	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $T_j = 110^{\circ}\text{C}$		MIN.	0.2	V
t _{gt}	$V_D = V_{DRM}$ $I_G = 40$ mA $dI_G/dt = 0.5$ A/µs		TYP.	2	μs
Ι _Η	I _T = 100 mA Gate open		MAX.	30	mA
١L	$I_{G} = 1.2 \times I_{GT}$		TYP.	50	mA
dV/dt	$ \begin{array}{ c c c c c } \mbox{Linear slope up to:} & & & \\ \mbox{V}_D = \ 67 \ \% \ \mbox{V}_{DRM} \ \mbox{Gate open} & & \\ \end{array} \ \ T_j = 110^{\circ} \mbox{C} \label{eq:Tj} $		MIN.	200	V/µs
V _{TM}	I _{TM} = 20 A tp = 380 μs		MAX.	1.6	V
I _{DRM}	V _{DBM} = V _{BBM}	$T_j = 25^{\circ}C$	MAX.	10	μA
I _{RRM}		T _j = 110°C		2	mA
t _q		T _j = 110°C	TYP.	70	μs

Tables 4: Electrical Characteristics (T_i = 25°C, unless otherwise specified)

Table 5: Thermal Resistance

Symbol	Parameter		Unit
R _{th(j-c)}	Junction to case (D.C.)	2.5	°C/W
R _{th(j-a)}	Junction to ambient	60	°C/W

Figure 1: Maximum average power dissipation versus average on-state current







57

P(W)

 $\alpha = 60$

2

 $\alpha = 30$

12

10

8

6

4

2

0

Figure 3: Average on-state current versus case temperature



Figure 5: Relative variation of gate trigger current versus junction temperature



Figure 7: Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp < 10 ms, and corresponding values of l²t



Figure 4: Relative variation of thermal impedance versus pulse duration



Figure 6: Surge peak on-state current versus number of cycles







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Figure 9: Ordering Information Scheme

	TYN 4 10	RG
Standard SCR series		
Voltage		
4 = 400V		
Current		
10 = 10A		
Packing mode		
RG = Tube		

Table 6: Product Selector

Part Numbers		Voltage (xxx)		Sensitivity	Package	
Fait Numbers	400 V	600 V	800V	Sensitivity		
TYN410RG	Х					
TYN610RG		Х		15 mA	TO-220AB	
TYN810RG			Х			





Figure 10: TO-220AB Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <u>www.st.com</u>.

Table 7: Ordering Information

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
TYN410RG	TYN410				
TYN610RG	TYN610	TO-220AB	2.3 g	50	Tube
TYN810RG	TYN810				

Table 8: Revision History

Date	Revision	Description of Changes
Sep-2001	1A	First issue.
13-Feb-2006	2	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.

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